

KSC2223

High Frequency Amplifier

- Very small size to assure good space factor in Hybrid IC applications
- f_T=600MHz (TYP.) at I_C=1mA
 C_{OB}=1pF (TYP.) at V_{CB}=6V
- NF=3dB (TYP.) at f=100MHz



1. Base 2. Emitter 3. Collector

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

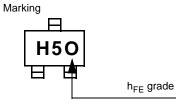
| Symbol | Parameter | Value | Units |
|------------------|---------------------------|-----------|-------|
| V _{CBO} | Collector-Base Voltage | 30 | V |
| V _{CEO} | Collector-Emitter Voltage | 20 | V |
| V _{EBO} | Emitter-Base Voltage | 4 | V |
| I _C | Collector Current | 20 | mA |
| P _C | Collector Dissipation | 150 | mW |
| T _J | Junction Temperature | 150 | °C |
| T _{STG} | Storage Temperature | -55 ~ 150 | °C |

Electrical Characteristics T_a=25°C unless otherwise noted

| Symbol | Parameter | Test Condition | Min. | Тур. | Max. | Units |
|-----------------------|--------------------------------------|--|------|------|------|-------|
| I _{CBO} | Collector Cut-off Current | $V_{CB=}30V$, $I_{E}=0$ | | | 0.1 | μΑ |
| h _{FE} | DC Current Gain | V _{CE} =6V, I _C =1mA | 40 | 90 | 180 | |
| V _{CE} (sat) | Collector Emitter Saturation Voltage | I _C =10mA, I _B =1mA | | 0.1 | 0.3 | V |
| C _{ob} | Output Capacitance | $V_{CB}=6V$, $I_{E}=0$, $f=1MHz$ | | 1 | | pF |
| f _T | Current Gain Bandwidth Product | V _{CE} =6V, I _C =1mA | 400 | 600 | | MHz |
| C _{c·rbb} | Time Constant | V _{CB} =6V, I _C =1mA f=31.9MHz | | 12 | | ps |
| NF | Noise Figure | V_{CE} =6V, I_{C} =1mA f=100MHz, R_{S} =50 Ω | | 3 | | dB |

h_{FE1} Classification

| Classification | R | 0 | Y |
|-----------------|---------|----------|----------|
| h _{FE} | 40 ~ 80 | 60 ~ 120 | 90 ~ 180 |



Typical Characteristics

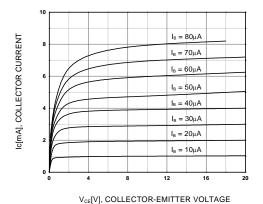


Figure 1. Static Characteristic

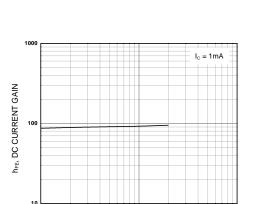


Figure 3. DC current Gain 2

 $V_{CE}[V]$, COLLECTOR-EMITTER VOLTAGE

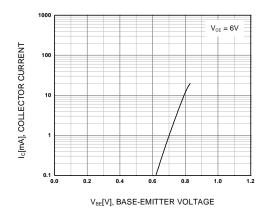


Figure 5. Base-Emitter On Voltage

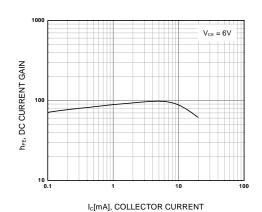


Figure 2. DC current Gain 1

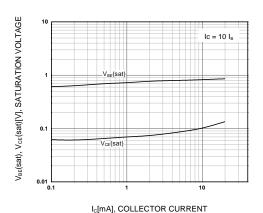


Figure 4. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

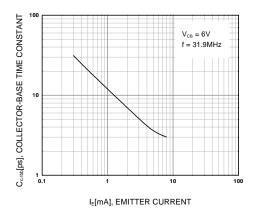


Figure 6. Collector-Base Time Constant

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Typical Characteristics (Continued)

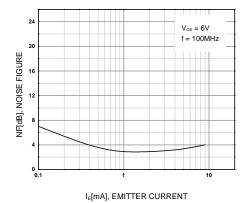


Figure 7. Noise Figure

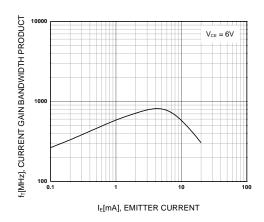


Figure 8. Current Gain Bandwidth Product

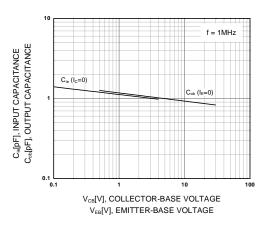


Figure 9. Input and Output Capacitance

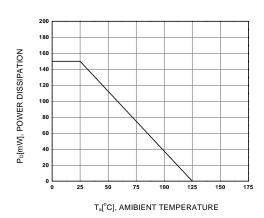
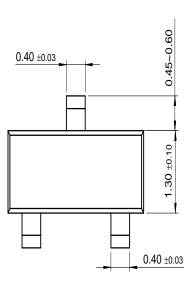
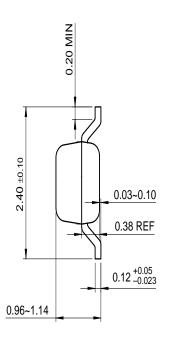


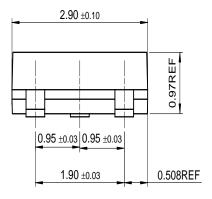
Figure 10. Power Derating

Package Demensions

SOT-23







Dimensions in Millimeters

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| DenseTrench™ | HiSeC™ | QS TM | TinyLogic™ |
| DOME™ | ISOPLANAR™ | QT Optoelectronics™ | UHC™ |
| EcoSPARK™ | LittleFET™ | Quiet Series™ | UltraFET [®] |
| E ² CMOS™ | MicroFET™ | SLIENT SWITCHER® | VCX™ |
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